

Low Capacitance Bidirectional TVS/ESD Protection Diode

DESCRIPTION

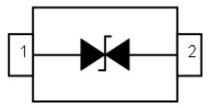
The SLESD5B5.0ST1G is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line applications.

This device has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

ORDERING INFORMATION

- ♦ Device: SLESD5B5.0ST1G
- ♦ Package: SOD-523
- ♦ Marking: LB
- ♦ Material: Halogen free
- ♦ Packing: Tape & Reel
- ♦ Quantity per reel: 3,000pcs

PIN CONFIGURATION



FEATURES

- ♦IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- \diamond Peak power dissipation: 35W (8/20µs)
- ♦ Protects one directional I/O line
- \diamond Low clamping voltage
- ♦Working voltages : 5V
- ♦Low leakage current
- ♦Low capacitance

MACHANICAL DATA

- \diamond SOD-523 package
- ♦ Packaging: Tape and Reel
- ♦ Reel size: 7 inch
- ♦ Weight: 0.001 gram (approx.)

APPLICATIONS

- ♦ High Speed Line :USB1.0/2.0, VGA, DVI, SDI,
- ♦ Serial and Parallel Ports
- ♦Notebooks, Desktops, Servers
- ♦ Projection TV
- Cellular handsets and accessories
- \diamond Portable instrumentation
- \diamond Peripherals

PACKAGE OUTLINE



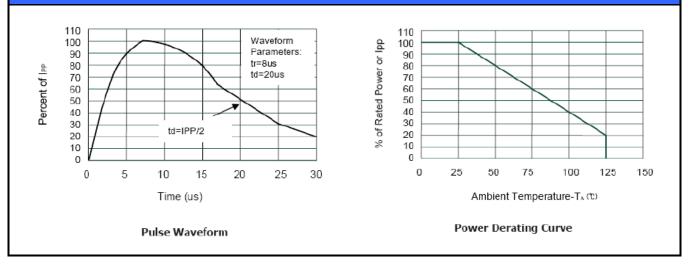


ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±15 ±8	kV				
P _{PP}	Peak Pulse Power (8/20µs)	35	W				
T _{OPT}	Operating Temperature	-55~150	°C				
T _{STG}	Storage Temperature	-55~150	°C				

ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
Symbol	Parameter	Test Condition	Min	Тур	Мах	Units			
V _{RWM}	Reverse Working Voltage				5.0	V			
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA	5.6		9.4	V			
I _R	Reverse Leakage Current	$V_{RWM} = 5V$			2.0	μA			
Vc	Clamping Voltage	$I_{PP} = 1A, t_p = 8/20 \mu s$			10.5	V			
		I _{PP} = 2A, t _p = 8/20μs			14.0	V			
CJ	Junction Capacitance	$V_R = 0V$, f = 1MHz		3.0	3.5	pF			



ELECTRICAL CHARACTERISTICS CURVE



SOD-523 PACKAGE OUTLINE DIMENSIONS

